

033792R003

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Lei LU, et al.

International Application No.: PCT/CN2003/000867

International Filing Date: October 16, 2003

U.S. Serial No.: To Be Assigned

Group Art Unit: To Be Assigned

Filed: : Herewith

Examiner: To Be Assigned

For: NANO-TWIN COPPER MATERIAL WITH ULTRAHIGH STRENGTH AND  
HIGH CONDUCTIVITY AND ITS PREPARATION METHOD

**INFORMATION DISCLOSURE STATEMENT**


Commissioner for Patents  
Washington, D.C. 20231

Sir:

Pursuant to the duty of disclosure under 37 C.F.R. 1.56, Applicants are enclosing an Information Disclosure Citation Form (PTO-1449) which lists the references noted in the International Search Report being filed herewith. U.S. Publication No. 2002/0015833 is a family member of CN1337475. U.S. Patent No. 5,431,803 is a family member of CN1105398.

It is respectfully requested that the cited documents be considered by the Examiner in the above-identified patent application and that the cited documents be made officially of record therein. It is further requested that a listing of the same appear on the face of any patent which may issue from this application.

Respectfully submitted,  
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April 26, 2005

FORM PTO-1449  <b>INFORMATION DISCLOSURE STATEMENT</b>	ATTY. DOCKET 033792R003	SERIAL NO. <del>To Be Assigned</del>
	APPLICANT: Lei LU, et al.	
	FILING DATE 4/26/05 <del>Herewith</del>	GROUP ART UNIT 1793 <del>To Be Assigned</del>

## U.S. PATENT DOCUMENTS

*Examiner's Initials		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE, IF APPROPRIATE
/S.I./	AA	2002/0015833	2/7/02	Takahashi et al.			
/S.I./	AB	5,431,803	7/11/95	DiFranco et al.			
	AC						
	AD						
	AF						
	AC						
	AH						
	AI						
	AJ						
	AK						

## FOREIGN PATENT DOCUMENTS

*Examiner's Initials		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION YES NO
/S.I./	AL	1 337 475	2/27/02	China			Abstract
/S.I./	AM	1 105 398	7/19/95	China			Abstract

## OTHER INFORMATION (Including Author, Title, Date, Pertinent Pages, Etc.)

/S.I./	AN	Abstract for CN 1389597 having a publication date of January 8, 2003 for invention entitled "High-strength and high-conductivity nanometer crystal copper material and its prepn"
	AO	
EXAMINER: /Siky'in Ip/		DATE CONSIDERED: 06/18/2009
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.		